Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
•		"5,967,795" 5,712,503; Ueno, et "al.", U.S. "Pat." "No." "5,789,311"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:41
L1	5506	filed near (shield plate relief)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:43
L2	10762	field near (shield plate relief)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:43
L3	73294	soi or silicon-on-insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:43
L4	17576	bipolar same (pnp or npn)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:32
L5	1028	I3 and I4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:44
L6	72	I5 and (field near (plate or electrode or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:48
L7	813	I5 and gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:45

L8	8246	257/347,350,351;526,E27.112,E29. 009,E29.01,E29.182,E29.184.ccls. 438/152,155.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:46
L9	22788584	@ad<"20020604" @rlad<"20020604"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:46
L10	57	16 and 19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:46
L11	51	I5 and I2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:48
L12	78	l11 andl9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:48
L13	38	111 and 19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:00
L14	557	(field near plates) same (double multiple second two) and (bipolar bjt) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:00
L15	603	(field near plates) same (double multiple second two) and (bipolar bjt pnp npn) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:09

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L16	113	(field near plates) same (double multiple second two) same (bipolar bjt pnp npn) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:09
L17	626	(field near plates metallization) same (double multiple second two) same (bipolar bjt pnp npn) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:09
L18	2	"5198379".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:11
L19	0	filed near plate and electrically near shield and (bjt bipolar near transistor) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:11
L20	0	filed near plates and electrically near shield and (bjt bipolar near transistor) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:11
L21	0	filed near plates same electrically near shield and (bjt bipolar near transistor) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:12
L22	0	field near plates same electrically near shield and (bjt bipolar near transistor) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:13
L23	16	electrically near shield and (bjt bipolar near transistor) and I9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:18

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L24	33732	pnp near transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:18
L25	1	pnp near transistor and filed near plates	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:19
L26	192	pnp near transistor and field near plates	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/09/21 13:19
L27	153	pnp near transistor and field near plates and 19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:30
L28	2	("6252248").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/21 13:32
L29	11531	(bipolar same (pnp or npn)) near transistor bjt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:33
L30	11	(("6190948") or ("5420457") or ("5440161") or ("5731627") or ("5973341") or ("6118154")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/21 13:34
L31	6	(("6190948") or ("5420457") or ("5440161") or ("5731627") or ("5973341") or ("6118154")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2006/09/21 13:36

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L32	1	filed near plate and bjt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:36
L33		field near plate and bjt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 13:41
S1 .	5479	filed near (shield plate relief)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/21 12:42
S2	10331	field near (shield plate relief)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 17:52
S3	67783	soi or (silicon near on near insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 17:52
S4	546	S2 and S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	ON	2006/04/25 17:52
S5	362	S4 and @ad<"20020604"	IBM_TDB US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2006/04/25 17:58
S6	304	S4 and metal\$8 and (@ad<"20020604" or @rlad<"20020604")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/25 18:02

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S7	298	S4 and metal\$8 and (@ad<"20020604" or @rlad<"20020604") and between	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR	ON	2006/04/25 18:02
			DERWENT; IBM_TDB			
S8	39	("4065781"   "4091527"   "4309715"   "4313809"   "4507846"   "4700454"   "4766482"   "4778775"   "4907053").PN. OR ("4996575").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/25 18:04
S9	48	("20010030722"   "20020080295"   "20020093019"   "20030038303"   "4609930"   "4748485"   "4977105"   "4984033"   "4996575"   "5034788"   "5103277"   "5124769"   "5140391"   "5185535"   "5198379"   "5233211"   "5246882"   "5273921"   "5275972"   "5281840"   "5294821"   "5315132"   "5327001"   "5359219"   "5371398"   "5420048"   "5463483"   "5470793"   "5475238"   "5485019"   "5506436"   "5521107"   "5532850"   "5580802"   "5604368"   "5621224"   "5646424"   "5702963"   "5807772"   "5818076"   "5917221"   "6054734"   "6225150"   "6252248"   "6323068"   "6330044"   "6479333"   "6603453").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/25 18:28
S10	14	(S9 S8 S7) and adhesive	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/25 18:29
S11	2	("5198379").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2006/04/26 11:47

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